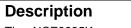


NCE N-Channel Enhancement Mode Power MOSFET



The NCE3095K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

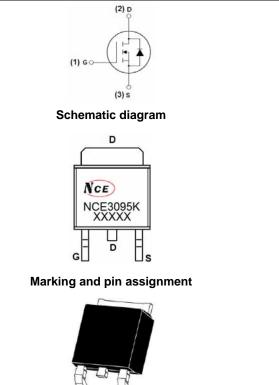
General Features

- V_{DS} =30V,I_D =95A
 - $R_{DS(ON)}$ <5.1m Ω @ V_{GS}=10V
 - $R_{DS(ON)} < 8.5 m\Omega @ V_{GS} = 5V$
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3095K	NCE3095K	TO-252-2L	-	-	-

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	95	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	67.2	А
Pulsed Drain Current (Note 1)	I _{DM}	380	A
Maximum Power Dissipation	PD	100	W
Derating factor		0.67	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	150	mJ
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	1.5	°C/W]
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Electrical Characteristics (TC=25°C unless otherwise noted)

Symbol	Condition	Min	Тур	Max	Unit
	·				
BV _{DSS}	V _{GS} =0V I _D =250µA	30	-	-	V
I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
	·				
V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1	1.5	2.2	V
5	V _{GS} =10V, I _D =20A	-	4.1	5.1	mΩ
RDS(ON)	V _{GS} =4.5V, I _D =15A	-	5.5	8.5	
g fs	V _{DS} =5V,I _D =20A	30	-	-	S
	·				
Clss		-	1784	-	PF
C _{oss}		-	266	-	PF
C _{rss}		-	212	-	PF
	·				
t _{d(on)}		-	7	-	nS
tr	V _{DD} =5V,I _D =20A	-	6	-	nS
t _{d(off)}	V_{GS} =10V, R_{GEN} =6 Ω	-	30	-	nS
t _f		-	8	-	nS
Qg		-	38.4	-	nC
Q _{gs}		-	5.8	-	nC
Q _{gd}	V _{GS} -10V	-	7.9	-	nC
	·				
V _{SD}	V _{GS} =0V,I _S =20A	-	0.85	1.2	V
Is		-	-	95	Α
t _{rr}	TJ = 25°C, I _F = 20A	-	-	47	nS
Qrr	di/dt = 100A/µs ^(Note3)	-	-	25	nC
t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				
	BVDSS IDSS IGSS VGS(th) RDS(ON) GFS Clss Clss Clss Crss td(on) tr Qg Qgs Qgd VSD Is trr	$ \begin{array}{ c c c c c } \hline & & & & & & & & & & & & & & & & & & $	$ \begin{array}{ c c c c c c } \hline P & V_{GS} & V_{GS} = 0V \ I_{D} = 250 \mu A & 30 \\ \hline I_{DSS} & V_{DS} = 30V, V_{GS} = 0V & - \\ \hline I_{GSS} & V_{GS} = \pm 20V, V_{DS} = 0V & - \\ \hline & V_{GS}(h) & V_{DS} = V_{GS}, I_{D} = 250 \mu A & 1 \\ \hline & V_{GS}(n) & V_{GS} = 10V, \ I_{D} = 20A & - \\ \hline & V_{GS} = 10V, \ I_{D} = 15A & - \\ \hline & V_{GS} & V_{DS} = 5V, I_{D} = 20A & 30 \\ \hline & C_{ISS} & V_{DS} = 5V, I_{D} = 20A & 30 \\ \hline & C_{ISS} & V_{DS} = 15V, V_{GS} = 0V, \\ \hline & C_{CSS} & F = 1.0MHz & - \\ \hline & t_{r} & V_{DD} = 5V, I_{D} = 20A & - \\ \hline & t_{r} & V_{DD} = 5V, I_{D} = 20A & - \\ \hline & t_{r} & V_{DS} = 15V, I_{D} = 20A & - \\ \hline & t_{r} & V_{DS} = 15V, I_{D} = 20A & - \\ \hline & t_{r} & V_{DS} = 15V, I_{D} = 20A & - \\ \hline & Q_{g} & V_{DS} = 15V, I_{D} = 20A & - \\ \hline & Q_{gd} & V_{GS} = 10V & - \\ \hline & V_{SD} & V_{GS} = 10V & - \\ \hline & V_{SD} & V_{GS} = 0V, I_{S} = 20A & - \\ \hline & I_{S} & - \\ \hline & t_{rr} & TJ = 25^{\circ}C, \ I_{F} = 20A & - \\ \hline & Q_{rr} & di/dt = 100A/\mu s^{(Note3)} & - \\ \hline \end{array}$	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$

Notes:

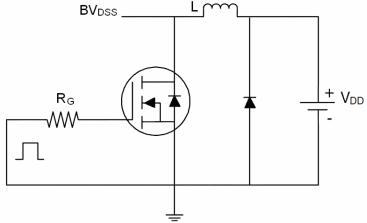
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: $Tj=25^{\circ}C$, $V_{DD}=15V$, $V_{G}=10V$, L=0.5mH, $Rg=25\Omega$



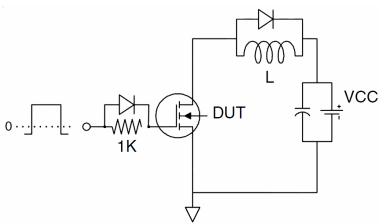
http://www.ncepower.com

Test Circuit

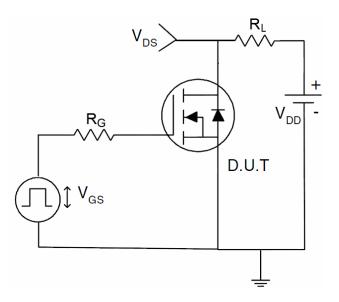
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit

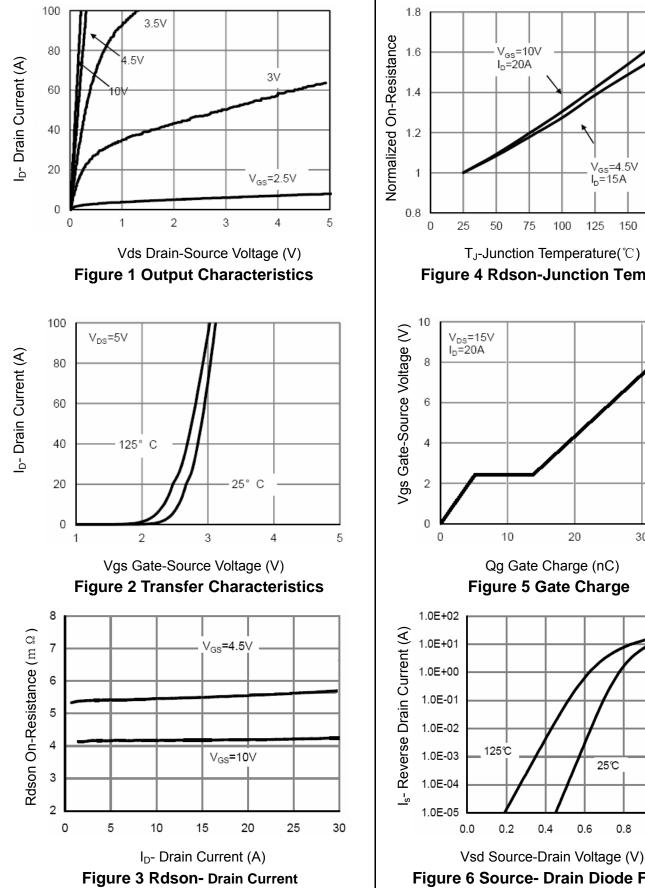


3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)



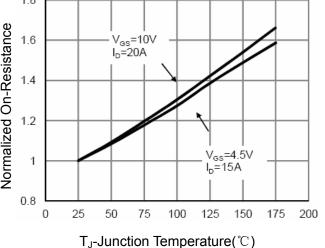


Figure 4 Rdson-Junction Temperature

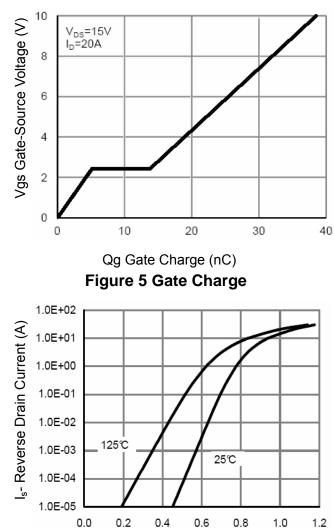


Figure 6 Source- Drain Diode Forward

0.8

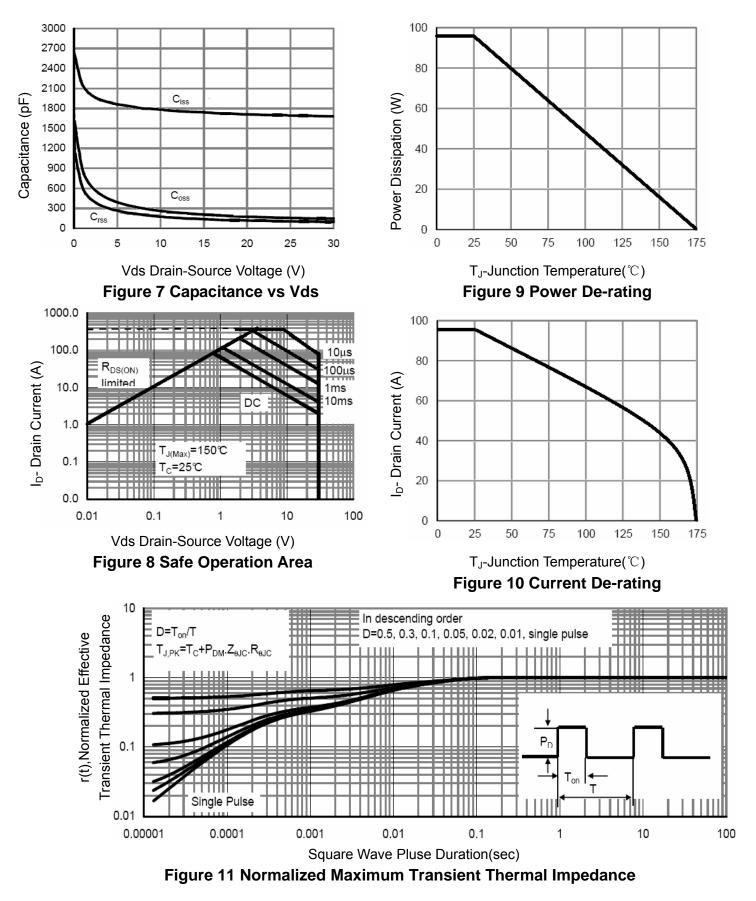
1.0

1.2



http://www.ncepower.com

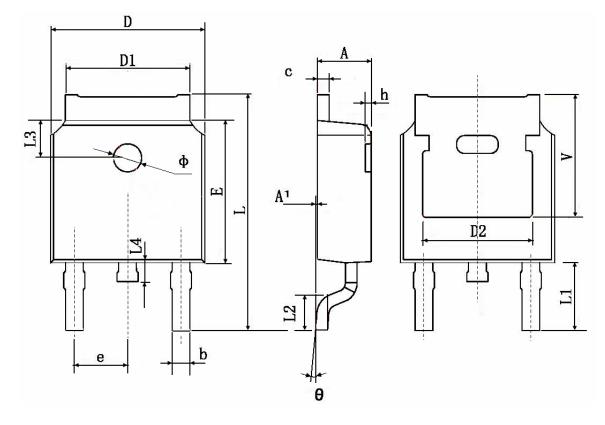
NCE3095K





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TO-252 Package Information



Querrale al	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.8	30 TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	D TYP.	0.211 TYP.		



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